


CR6CM

MEDIUM POWER USE
NON-INSULATED TYPE, GLASS PASSIVATION TYPE

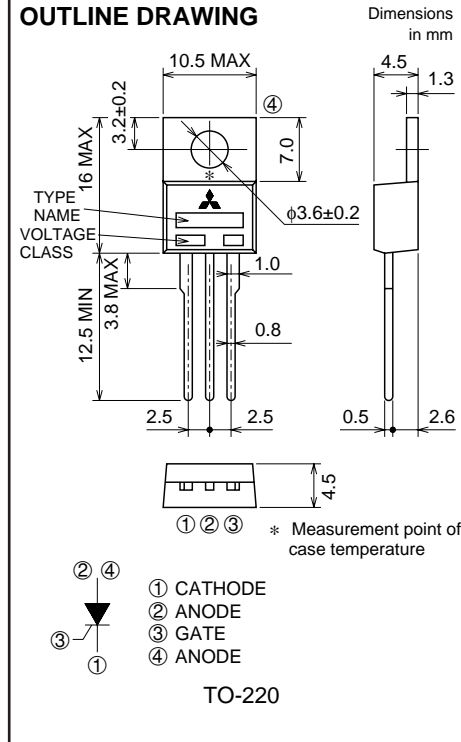
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- I_T (AV) 6A
- V_{DRM} 400V/600V
- I_{GT} 10mA

OUTLINE DRAWING

Dimensions in mm



TYPE NAME
VOLTAGE CLASS

① ② ③ * Measurement point of case temperature

① CATHODE
② ANODE
③ GATE
④ ANODE

TO-220

APPLICATION

Switching mode power supply, ECR, regulator for auticycle, motor control

MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		8	12	
VRRM	Repetitive peak reverse voltage	400	600	V
VRSM	Non-repetitive peak reverse voltage	500	720	V
VR (DC)	DC reverse voltage	320	480	V
VDRM	Repetitive peak off-state voltage	400	600	V
Vd (DC)	DC off-state voltage	320	480	V

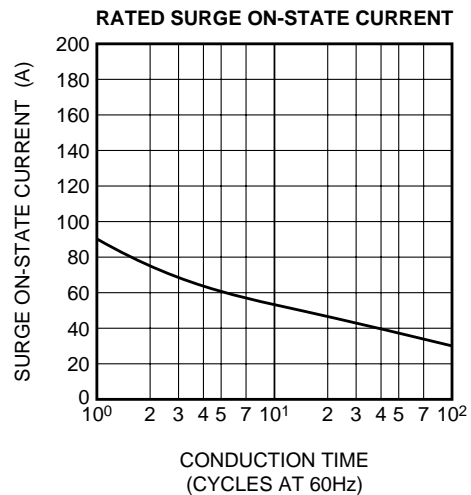
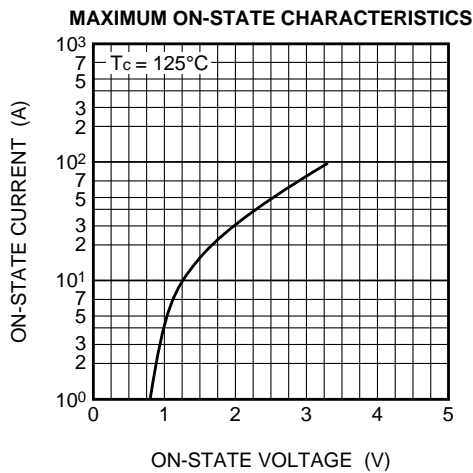
Symbol	Parameter	Conditions	Ratings	Unit
I_T (RMS)	RMS on-state current		9.4	A
I_T (AV)	Average on-state current	Commercial frequency, sine half wave, 180° conduction, $T_c=88^\circ\text{C}$	6	A
I_{TSM}	Surge on-state current	60Hz sine half wave 1 full cycle, peak value, non-repetitive	90	A
I^2_t	I^2_t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	34	A ² s
PGM	Peak gate power dissipation		5	W
PG (AV)	Average gate power dissipation		0.5	W
VFGM	Peak gate forward voltage		6	V
VRGM	Peak gate reverse voltage		10	V
IFGM	Peak gate forward current		2	A
T_j	Junction temperature		-40 ~ +125	°C
T_{stg}	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	2.0	g

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	$T_j=125^{\circ}\text{C}$, V_{RRM} applied	—	—	2.0	mA
IDRM	Repetitive peak off-state current	$T_j=125^{\circ}\text{C}$, V_{DRM} applied	—	—	2.0	mA
V _{TM}	On-state voltage	$T_c=25^{\circ}\text{C}$, $I_{TM}=20\text{A}$, instantaneous value	—	—	1.7	V
V _{GT}	Gate trigger voltage	$T_j=25^{\circ}\text{C}$, $V_D=6\text{V}$, $I_T=1\text{A}$	—	—	1.0	V
V _{GD}	Gate non-trigger voltage	$T_j=125^{\circ}\text{C}$, $V_D=1/2V_{DRM}$	0.2	—	—	V
I _{GT}	Gate trigger current	$T_j=25^{\circ}\text{C}$, $V_D=6\text{V}$, $I_T=1\text{A}$	—	—	10	mA
I _H	Holding current	$T_j=25^{\circ}\text{C}$, $V_D=12\text{V}$	—	15	—	mA
R _{th(j-c)}	Thermal resistance	Junction to case *1	—	—	3.0	$^{\circ}\text{C}/\text{W}$

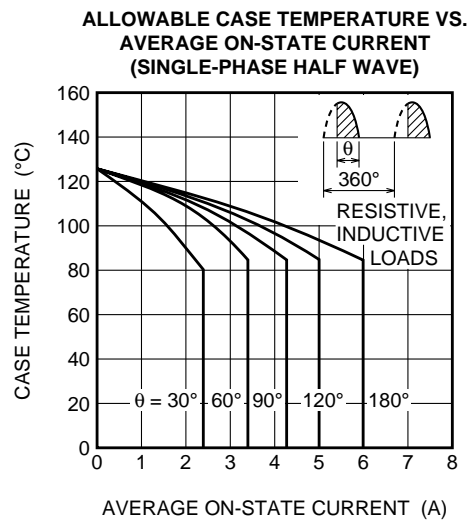
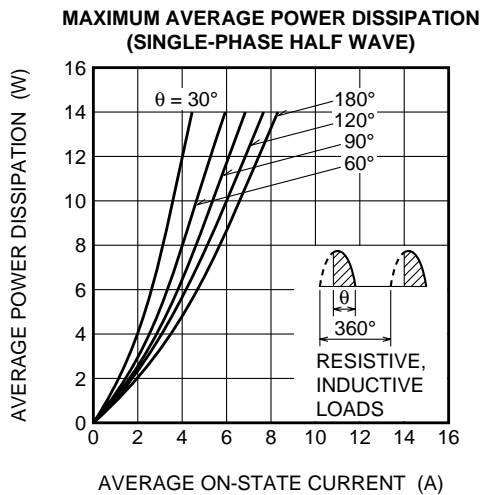
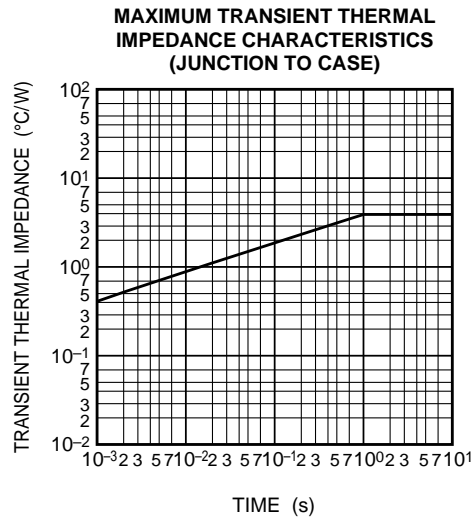
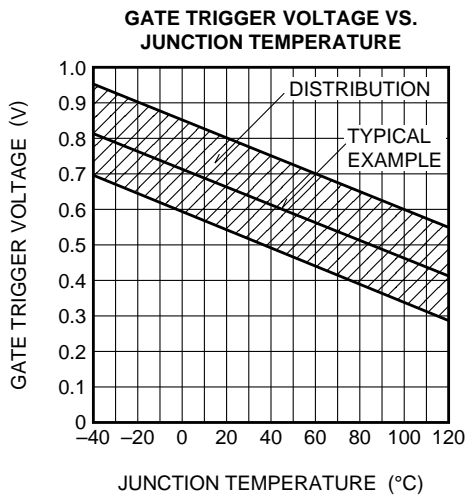
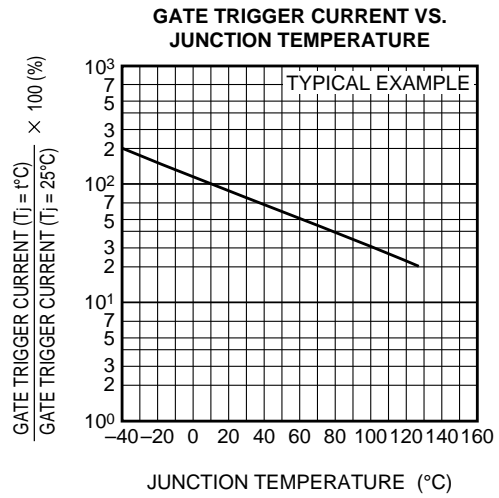
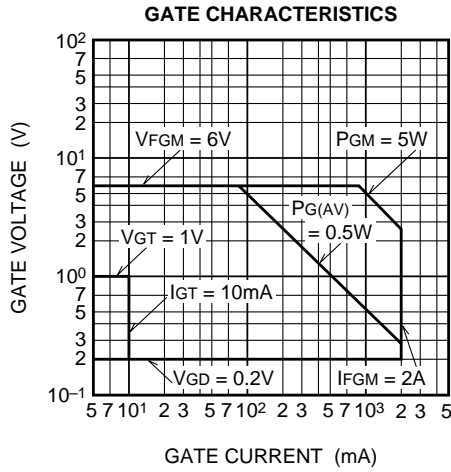
*1. The contact thermal resistance R_{th(j-c)} is 1.0 $^{\circ}\text{C}/\text{W}$ with greased.

PERFORMANCE CURVES



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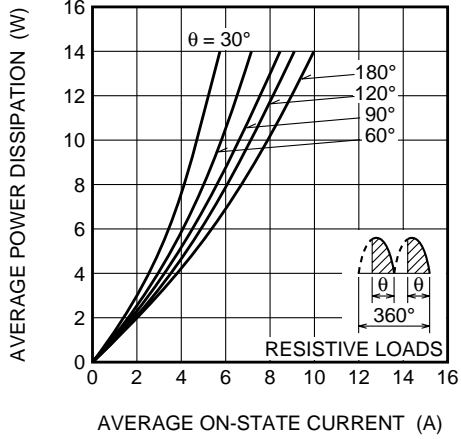


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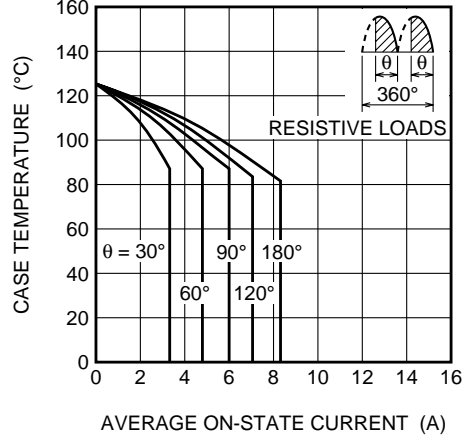
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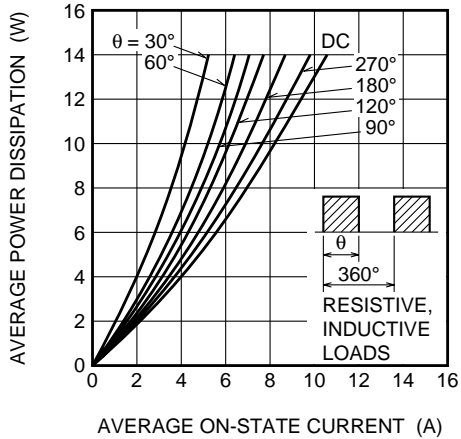
MAXIMUM AVERAGE POWER DISSIPATION (SINGLE-PHASE FULL WAVE)



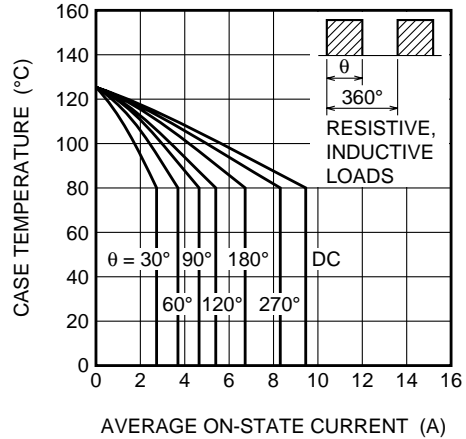
ALLOWABLE CASE TEMPERATURE VS. AVERAGE ON-STATE CURRENT (SINGLE-PHASE FULL WAVE)



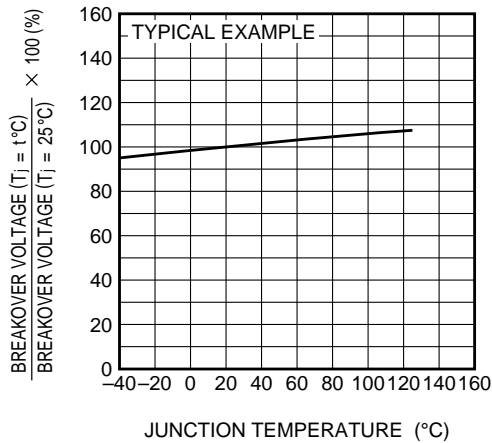
MAXIMUM AVERAGE POWER DISSIPATION (RECTANGULAR WAVE)



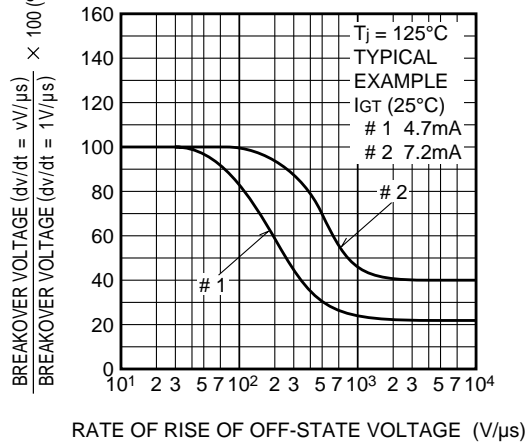
ALLOWABLE AMBIENT TEMPERATURE VS. AVERAGE ON-STATE CURRENT (RECTANGULAR WAVE)



BREAKOVER VOLTAGE VS. JUNCTION TEMPERATURE



BREAKOVER VOLTAGE VS. RATE OF RISE OF OFF-STATE VOLTAGE

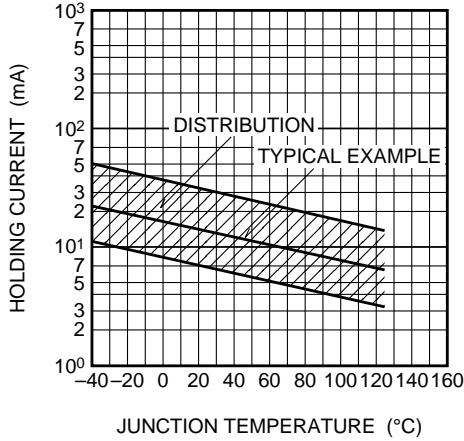


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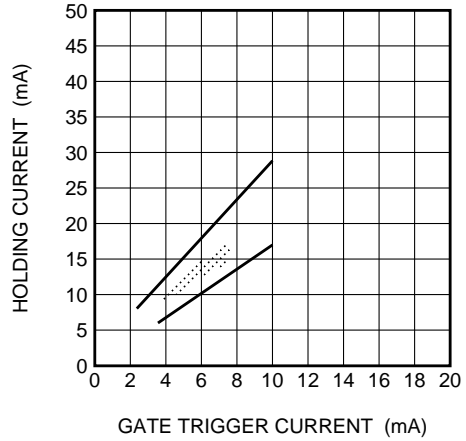
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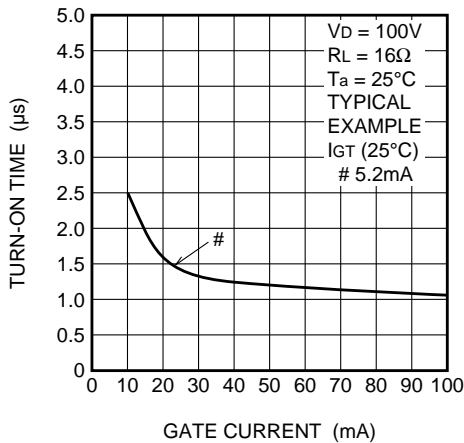
HOLDING CURRENT VS. JUNCTION TEMPERATURE



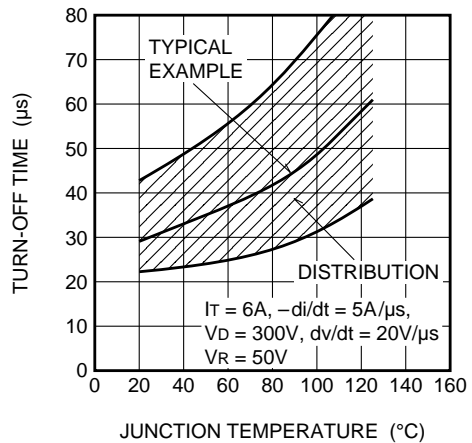
HOLDING CURRENT VS. GATE TRIGGER CURRENT



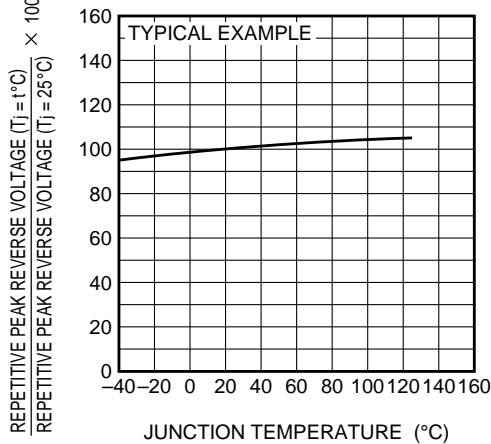
TURN-ON TIME VS. GATE CURRENT



TURN-OFF TIME VS. JUNCTION TEMPERATURE



REPETITIVE PEAK REVERSE VOLTAGE VS. JUNCTION TEMPERATURE



GATE TRIGGER CURRENT VS. GATE CURRENT PULSE WIDTH

